

## HIGH SPEED POWER DRIVER

Check for Samples: UC1705, UC2705, UC3705

#### **FEATURES**

- 1.5 A Source/Sink Drive
- 100 nsec Delay
- 40 nsec Rise Fall into 1000 pF
- Inverting and Non-Inverting Inputs
- Low Cross-Conduction Current Spike

- Low Quiescent Current
- 5 V to 40 V Operation
- Thermal Shutdown Protection
- Minidip and Power Packages

#### DESCRIPTION

The UC1705 family of power drivers is made with a high sppeed Schottky process to interface between low-level control functions and high-power switching devices - particularly power MOSFETs. These devices are also an optimum choise for capacitive line drivers where up to 1.5 A may be switched in either direction. With both inverting and non-inverting inputs available, logic signals of either polarity may be accepted, or one input can be used to gate or strobe the other.

Supply voltages for both  $V_S$  and  $V_C$  can independently range from 5 V to 40 V. For additional application details, see the UC1707/3707 data sheet (SLUS177).

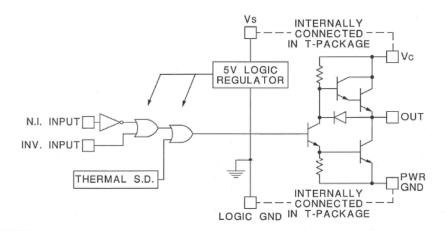
The UC1705 is packaged in an 8-pin hermetically sealed CERDIP for -55°C to 125°C operation. The UC3705 is specified for a temperature range of 0°C to 70°C and is available in either a plastic minidip or a 5-pin, power TO-220 package.

#### TRUTH TABLE(1)(2)

INV	N.I	OUT
Н	Н	L
L	Н	П
Н	L	L
L	L	L

- (1)  $\underline{OUT} = \overline{INV}$  and N.I.
- (2)  $\overline{OUT} = INV \text{ and N.i.}$

#### **BLOCK DIAGRAM**



A

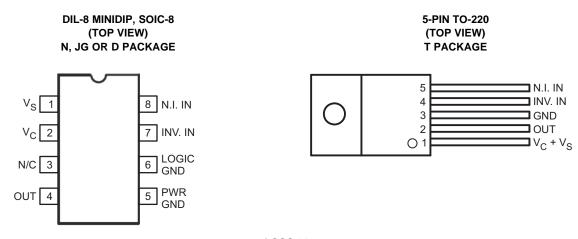
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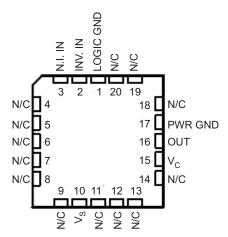


These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

### **CONNECTION DIAGRAMS**



LCCC-20 (TOP VIEW) FK PACKAGE





## **ABSOLUTE MAXIMUM RATINGS**(1)

		VALUE				
	N-Pkg	JG-Pkg	T-Pkg	UNIT		
Supply Voltage (V <sub>IN</sub> )	40	40	40	V		
Collector Supply Voltage, V <sub>C</sub>	40	40	40			
Output current (source or sink)						
Steady-State	±500	±500	±1	Α		
Peak Transient	±1.5	±1	±2	Α		
Capacitive Discharge Energy	20	15	50	μJ		
Digital Inputs (2)	5.5	5.5	5.5	V		
Power Dissipation at T <sub>A</sub> = 25°C <sup>(1)</sup>	1	1	3	W		
Power Dissipation at T <sub>A</sub> (Lead/Case) = 25°C <sup>(1)</sup>	3	2	25	W		
Operating Temperature Range	0 to 70	-55 to 125	0 to 70	°C		
Storage temperaturee	-65 to 150	-65 to 150	-65 to 150	°C		

<sup>(1)</sup> All currents are positive into, negative out of the specified terminal.

### **ELECTRICAL CHARACTERISTICS**

Unless otherwise stated, these specifications apply for  $T_A = -55^{\circ}\text{C}$  to +125°C for the UC1705, -25°C to +85°C for the UC2707, and 0°C to +70°C for the UC3705;  $V_{IN} = V_C = 20 \text{ V}$ .  $T_A = T_J$ .

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
.,	Curally suggest	V <sub>S</sub> = 40 V, outputs high, T package		6	8	mA
Vs	Supply current	V <sub>C</sub> = 40 V, outputs low, T package		6	12	mA
V <sub>C</sub>	Supply current (N, JG Only)	$V_C = 40 \text{ V}$ , outputs low		2	4	mA
V <sub>C</sub>	Leakage current (N, JG Only)	$V_S = 0, V_C = 30 \text{ V}$		0.05	0.1	mA
	Digital input low level				8.0	V
	Digital input high level		2.2			V
	Input current	V <sub>I</sub> = 0		-0.6	-1	mA
	Input leakage	V <sub>I</sub> = 5 V		0.05	0.1	mA
\/ \/	Output high acturation	$I_O = -50 \text{ mA}$			2	V
v <sub>C</sub> – v <sub>O</sub>	Output high saturation	$I_{O} = -500 \text{ mA}$			2.5	V
.,	Outrot law actions	I <sub>O</sub> = -50 mA			0.4	V
Vo	Output low saturation	$I_{O} = -500 \text{ mA}$			2.5	V
	Thermal shutdown			155		°C

<sup>(2)</sup> Digital Drive can exceed 5.5 V if the input current is limited to 10 mA



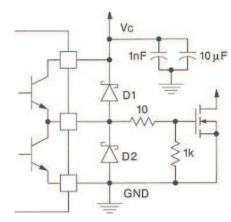
## TYPICAL SWITCHING CHARACTERISTICS

 $V_{IN} = V_C = 20 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ . Delays measured to 10% output change.

PARAMETER	TEST CONDITIONS	OUT	PUT CL =		UNIT
From Inv. Input to Output	open	1	2.2	nF	
Rise time delay		60	60	60	ns
10% to 90% rise		20	40	60	ns
Fall time delay		60	60	60	ns
90% to 10% fall		25	40	50	ns
From N.I. Input to Output					
Rise time delay		90	90	90	ns
10% to 90% rise		20	40	60	ns
Fall time delay		60	60	60	ns
90% to 10% fall		25	40	50	ns
V <sub>C</sub> cross-conduction current spike duration	Output rise	25			ns
	Output fall	0			ns

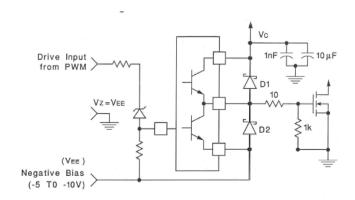


#### **APPLICATION INFORMATION**



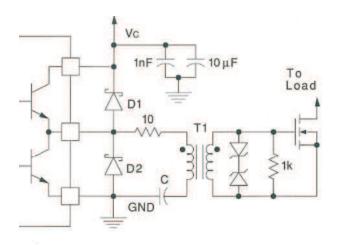
D1, D2: UC3611 Schottky Diodes

Figure 1. Power MOSFET Drive Circuit



D1, D2: UC3611 Schottky Diodes

Figure 2. Power MOSFET Drive Circuit Using Negative Bias Voltage and Level Shifting to Ground Referenced PWMs



D1, D2: UC3611 Schottky Diodes

Figure 3. Transformer Coupled MOSFET DRIVE Circuit

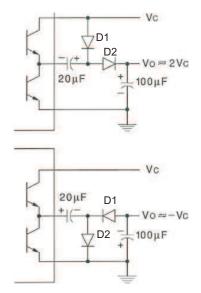


Figure 4. Charge Pump Circuit



## **REVISION HISTORY**

Cł	nanges from Revision C (December, 2011) to Revision D	Pag	E
•	Deleted SN54BCT373 from title for FK package image		2

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#### **PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	<b>Device Marking</b> (4/5)	Samples
5962-9579801M2A	ACTIVE	LCCC	FK	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 9579801M2A UC1705L/ 883B	Samples
5962-9579801MPA	ACTIVE	CDIP	JG	8	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	9579801MPA UC1705	Samples
5962-9579801VPA	ACTIVE	CDIP	JG	8	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	9579801VPA UC1705	Samples
UC1705J	ACTIVE	CDIP	JG	8	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	UC1705J	Samples
UC1705J883B	ACTIVE	CDIP	JG	8	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	9579801MPA UC1705	Samples
UC1705L883B	ACTIVE	LCCC	FK	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 9579801M2A UC1705L/ 883B	Samples
UC2705D	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	UC2705D	Samples
UC2705DG4	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	UC2705D	Samples
UC2705N	ACTIVE	PDIP	Р	8	50	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 85	UC2705N	Samples
UC3705D	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	0 to 70	UC3705D	Samples
UC3705DTR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	0 to 70	UC3705D	Samples
UC3705J	ACTIVE	CDIP	JG	8	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	0 to 70	UC3705J	Samples
UC3705N	ACTIVE	PDIP	Р	8	50	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	UC3705N	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.



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(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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#### OTHER QUALIFIED VERSIONS OF UC1705, UC1705-SP, UC3705, UC3705M:

Catalog: UC3705, UC1705, UC3705M, UC3705

Military: UC1705, UC1705

• Space : UC1705-SP

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications



# **PACKAGE OPTION ADDENDUM**

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• Space - Radiation tolerant, ceramic packaging and qualified for use in Space-based application

# **PACKAGE MATERIALS INFORMATION**

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### TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	U	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
UC3705DTR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

# **PACKAGE MATERIALS INFORMATION**

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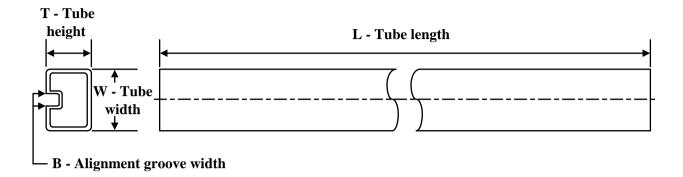
#### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
UC3705DTR	SOIC	D	8	2500	356.0	356.0	35.0	

# **PACKAGE MATERIALS INFORMATION**

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### **TUBE**



\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
5962-9579801M2A	FK	LCCC	20	1	506.98	12.06	2030	NA
UC1705L883B	FK	LCCC	20	1	506.98	12.06	2030	NA
UC2705D	D	SOIC	8	75	506.6	8	3940	4.32
UC2705DG4	D	SOIC	8	75	506.6	8	3940	4.32
UC2705N	Р	PDIP	8	50	506	13.97	11230	4.32
UC3705D	D	SOIC	8	75	506.6	8	3940	4.32
UC3705N	Р	PDIP	8	50	506	13.97	11230	4.32

8.89 x 8.89, 1.27 mm pitch

LEADLESS CERAMIC CHIP CARRIER

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





SMALL OUTLINE INTEGRATED CIRCUIT



### NOTES:

- 1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



#### NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



## JG (R-GDIP-T8)

#### **CERAMIC DUAL-IN-LINE**



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification.
- E. Falls within MIL STD 1835 GDIP1-T8

# P (R-PDIP-T8)

## PLASTIC DUAL-IN-LINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001 variation BA.



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